



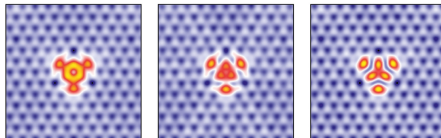
Benjamin Geisler (Autor)

Transition Metals and Silicon

Magnetic Properties of Thin Films, Impurities, and Heusler Alloys on the Atomic Scale

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Magnetic Properties of Thin Films,
Impurities, and Heusler Alloys
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